



# HMUN206

Low-Saturation Motor Driver for Low-Voltage Applications

## Description

The HMUN206 is a low-saturation motor driver IC for use in low-voltage applications. The HMUN206 is a bipolar stepper motor driver IC that is ideal for use in Printers, FDDS, Cameras, Video Cameras, VCD Players and other portable devices.

## Features

- Low voltage operation
- Low saturation voltage (<500mV, if IC at 1A current)
- Brake function
- Spark killer diodes built in
- Small and light
- Small motor driver circuits used in other electronics equipment

## Applications

- Video cameras
- Cameras
- Portable CD players
- Other portable products about small motor driver

## Absolute Maximum Ratings

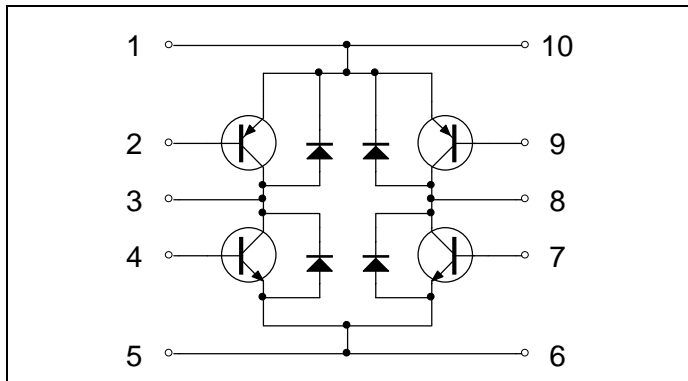
- Maximum Temperatures
  - Storage Temperature ..... -55 ~ +150 °C
  - Junction Temperature ..... +150°C Maximum
- Maximum Power Dissipation
  - PNP Total Power Dissipation (Ta=25°C±2°C)..... 750 mW
  - NPN Total Power Dissipation (Ta=25°C±2°C) ..... 750 mW
- Maximum Voltages and Currents (Ta=25°C±2°C)
  - PNP VCBO Collector to Base Voltage..... 40 V
  - NPN VCBO Collector to Base Voltage ..... 40 V
  - PNP VCEO Collector to Emitter Voltage ..... 25 V
  - NPN VCEO Collector to Emitter Voltage ..... 20 V
  - PNP VEBO Emitter to Base Voltage..... 6 V
  - NPN VEBO Emitter to Base Voltage ..... 7 V
  - PNP IC Collector Current (Continuous)..... 1.5 A
  - NPN IC Collector Current (Continuous)..... 2 A
  - PNP IC Collector Current (Peak PT=10ms) ..... 3 A
  - NPN IC Collector Current (Peak PT=10ms) ..... 4 A



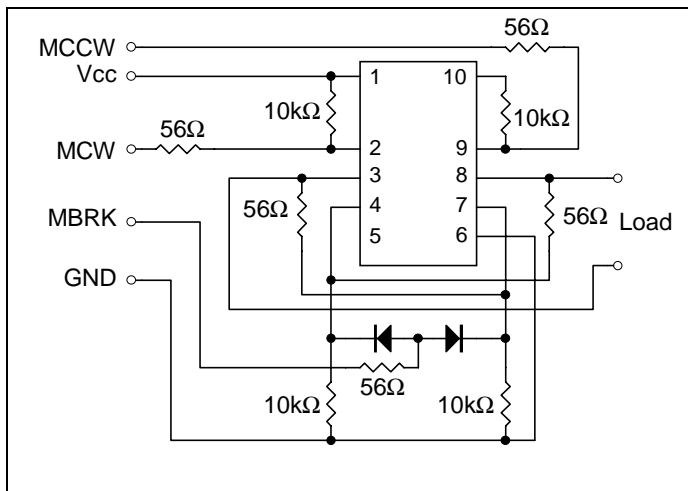
### Characteristics (Ta=25°C \*Pulse Test : Pulse Width ≤380us, Duty Cycle≤2%)

Symbol	Condition	Min.	Typ.	Max.	Unit
BV <sub>CB0</sub>	(PNP) I <sub>C</sub> =100uA, I <sub>E</sub> =0	40	-	-	V
	(NPN) I <sub>C</sub> =100uA, I <sub>E</sub> =0	40	-	-	V
BV <sub>CEO</sub>	(PNP) I <sub>C</sub> =2mA, I <sub>B</sub> =0	25	-	-	V
	(NPN) I <sub>C</sub> =1mA, I <sub>B</sub> =0	20	-	-	V
BV <sub>EBO</sub>	(PNP) I <sub>E</sub> =100uA, I <sub>C</sub> =0	6	-	-	V
	(NPN) I <sub>E</sub> =10uA, I <sub>C</sub> =0	7	-	-	V
I <sub>CBO</sub>	(PNP) V <sub>CB</sub> =35V, I <sub>E</sub> =0	-	-	100	nA
	(NPN) V <sub>CB</sub> =10V, I <sub>E</sub> =0	-	-	100	nA
I <sub>EBO</sub>	(PNP) V <sub>EB</sub> =6V, I <sub>C</sub> =0	-	-	100	nA
	(NPN) V <sub>EB</sub> =7V, I <sub>C</sub> =0	-	-	100	nA
*V <sub>CE(sat)</sub>	(PNP) I <sub>C</sub> =0.8A, I <sub>B</sub> =80mA	-	0.25	-	V
	(NPN) I <sub>C</sub> =1A, I <sub>B</sub> =100mA	-	0.35	-	V
*h <sub>FE</sub>	(PNP) V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	85	-	500	
	(NPN) V <sub>CE</sub> =2V, I <sub>C</sub> =500mA	230	-	800	
f <sub>T</sub>	(PNP) V <sub>CE</sub> =10V, I <sub>C</sub> =50mA	100	-	-	MHz
	(NPN) V <sub>CE</sub> =6V, I <sub>E</sub> =50mA	-	150	-	MHz
C <sub>ob</sub>	(PNP)	-	-	--	pF
	(NPN) V <sub>CB</sub> =20V, f=1MHz, I <sub>E</sub> =0	-	-	50	pF

### Equivalent Circuit

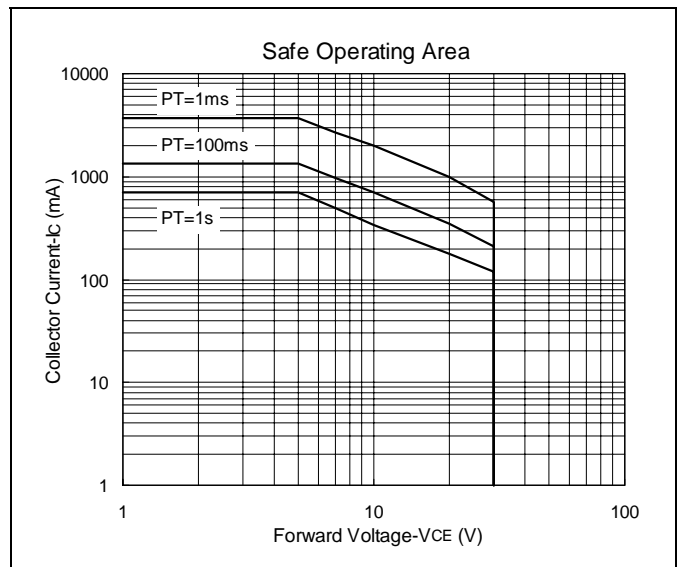
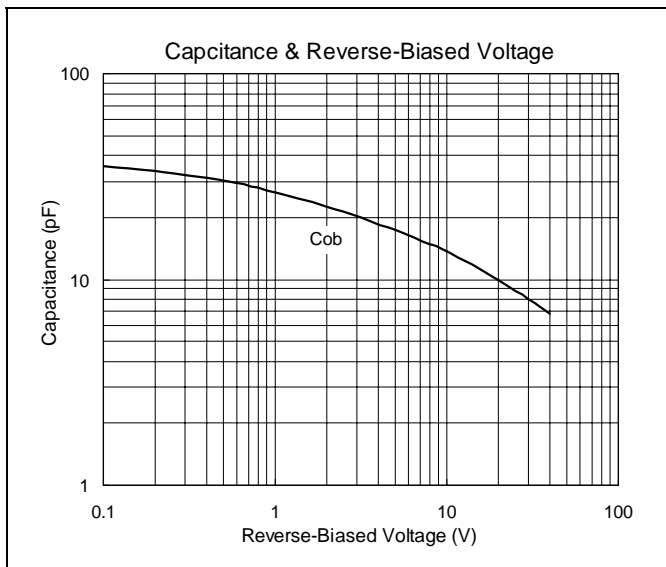
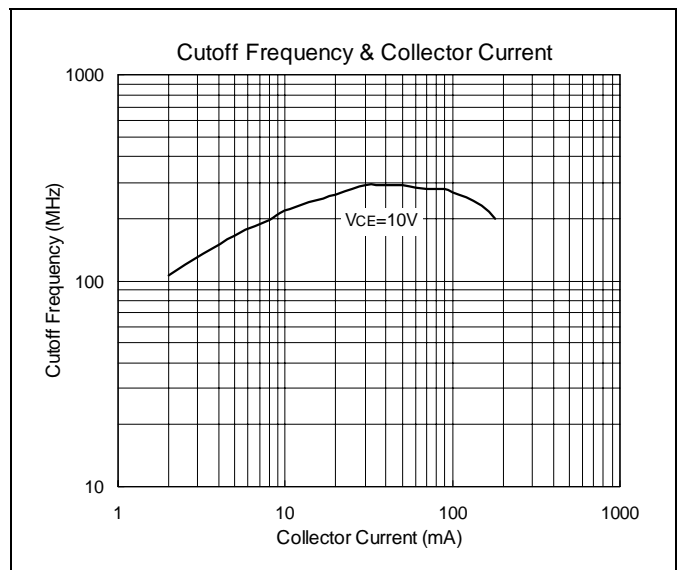
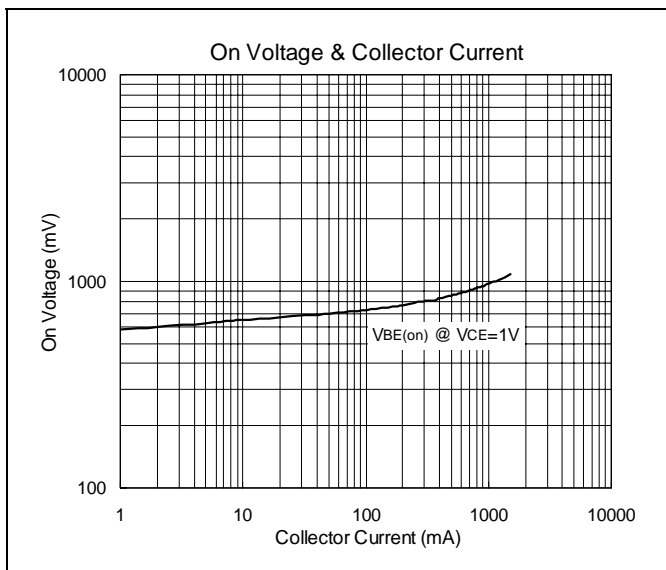
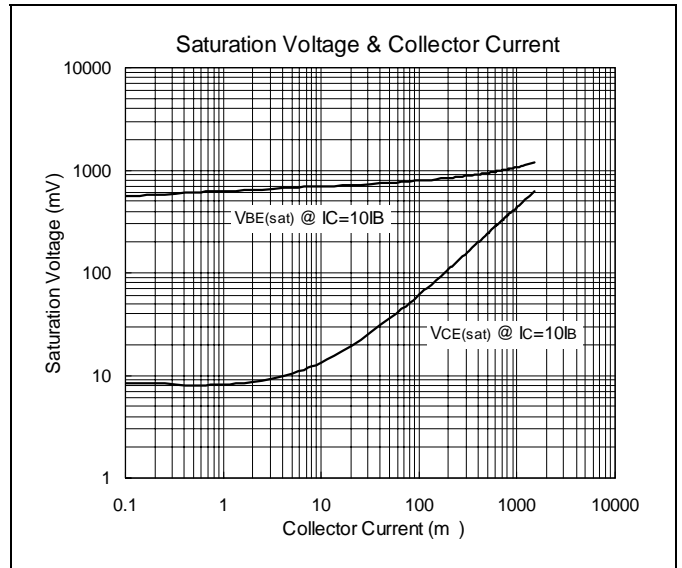
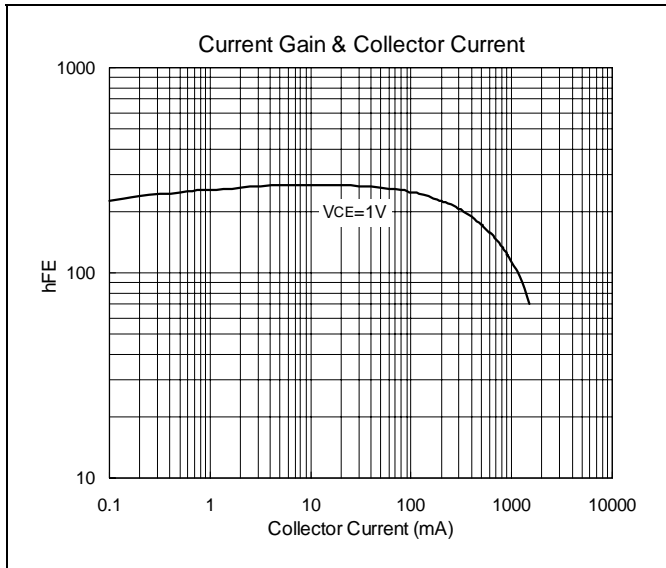


### Application Circuit



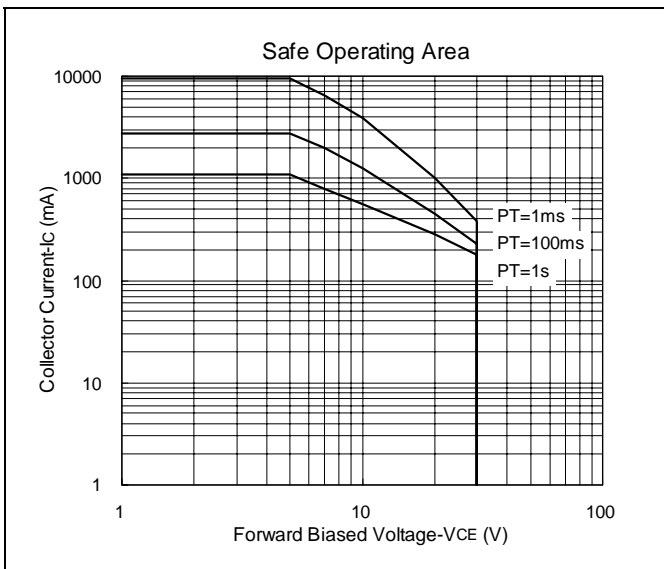
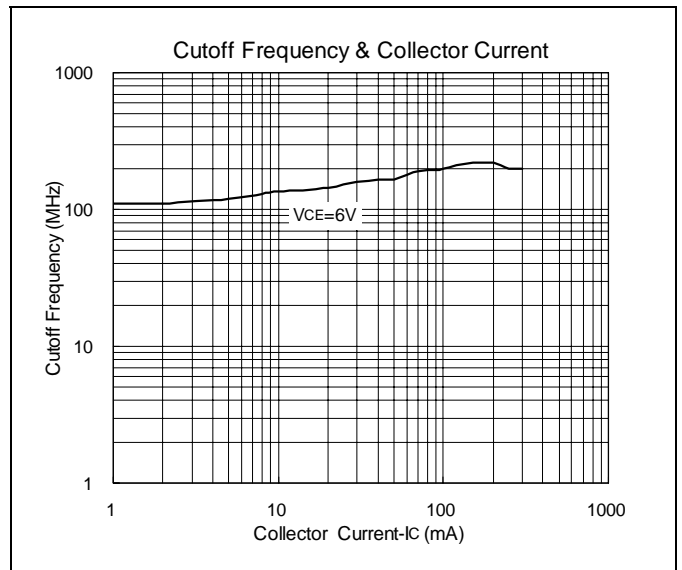
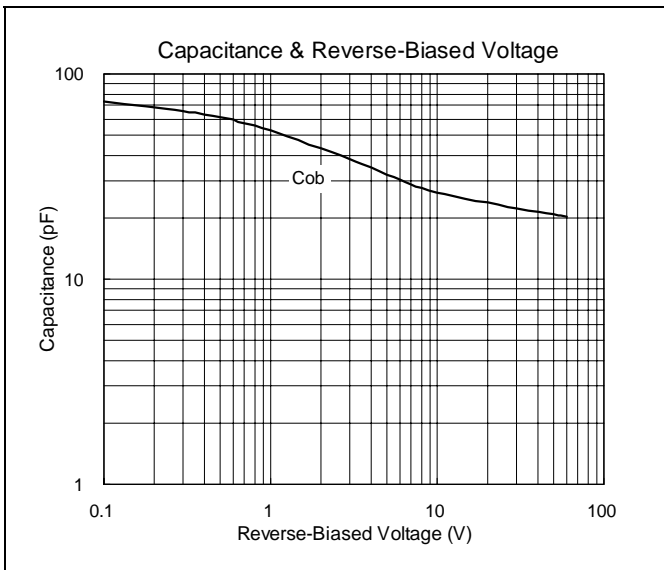
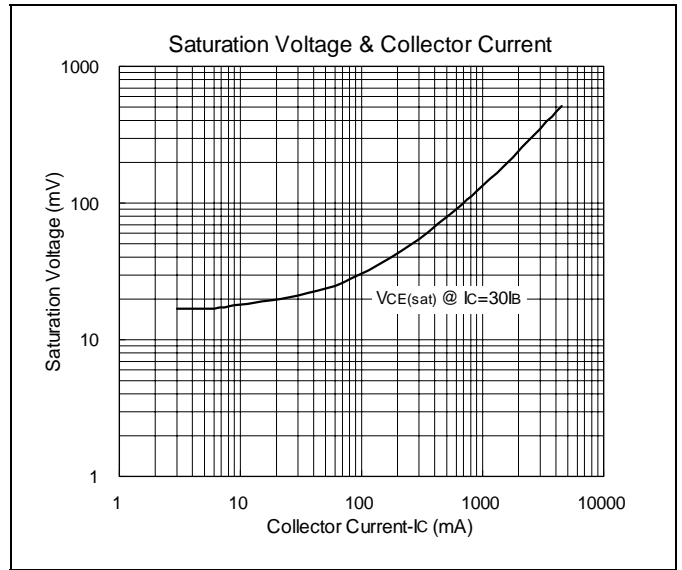
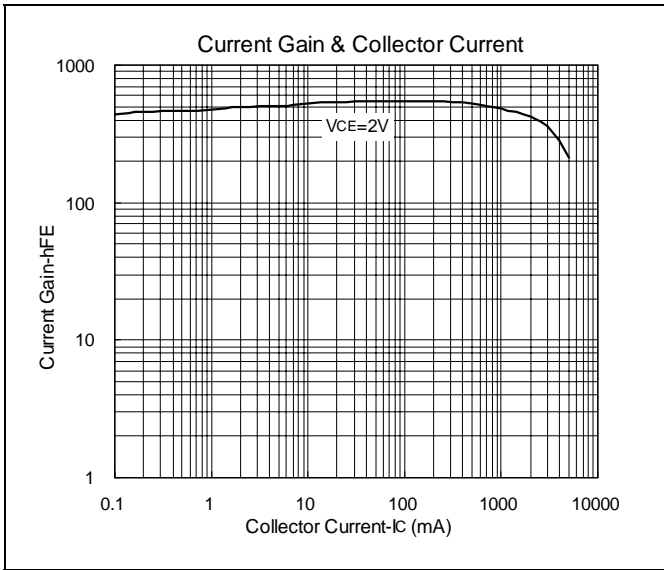


### PNP Transistor Characteristics Curve



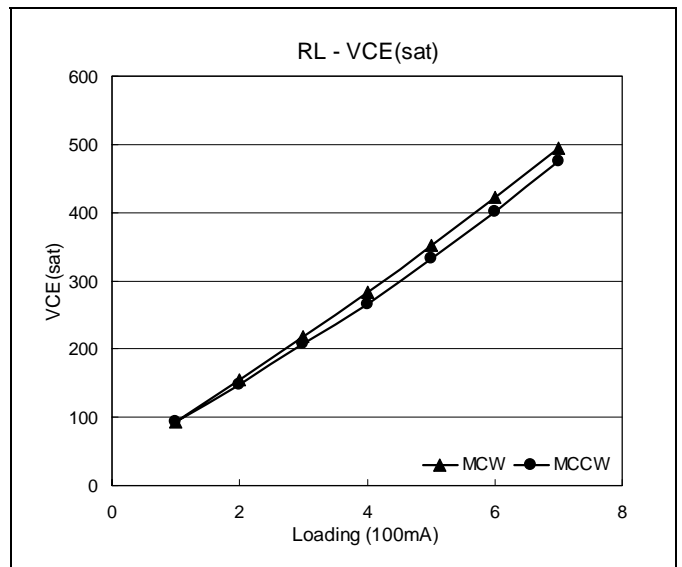
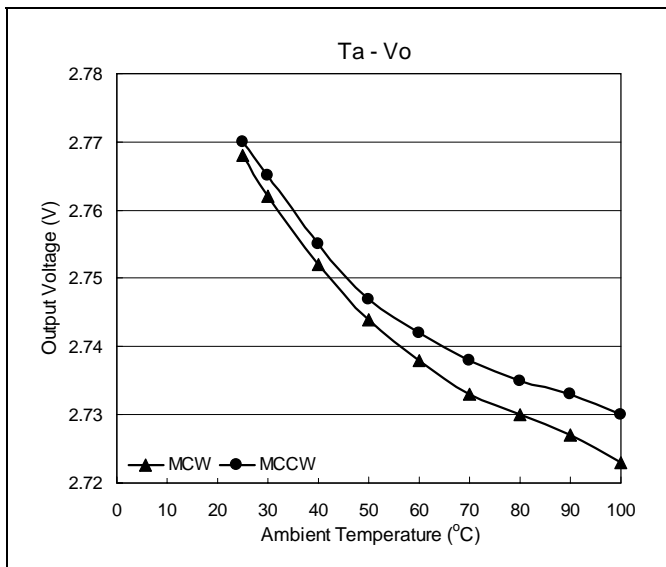
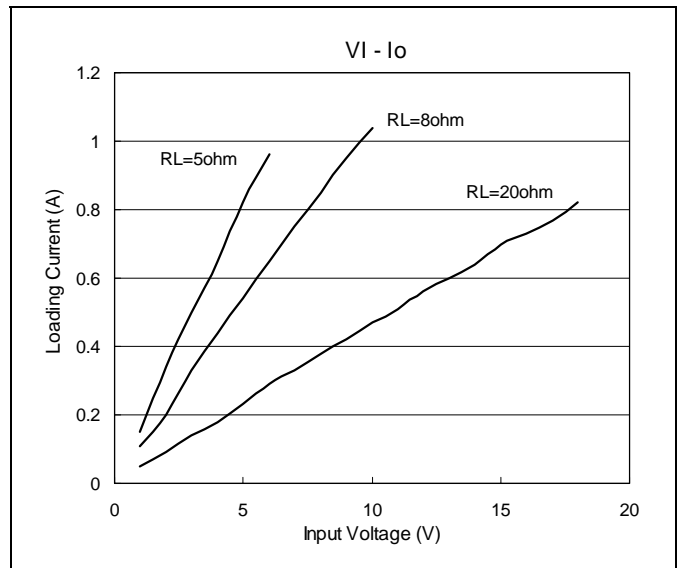
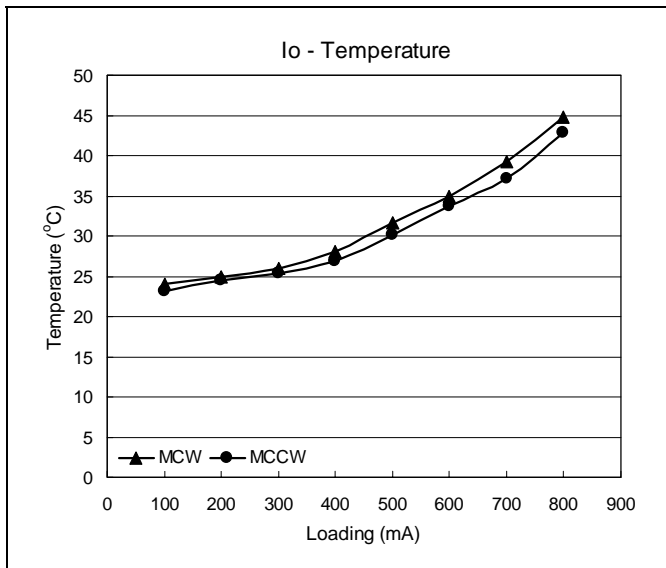
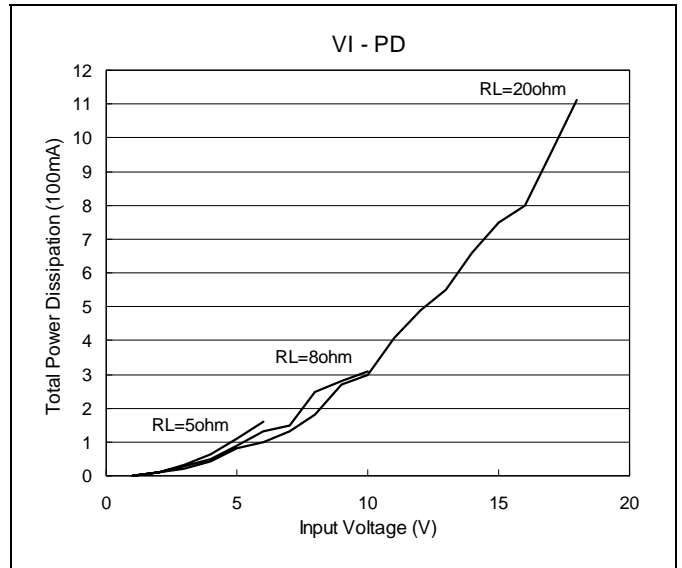
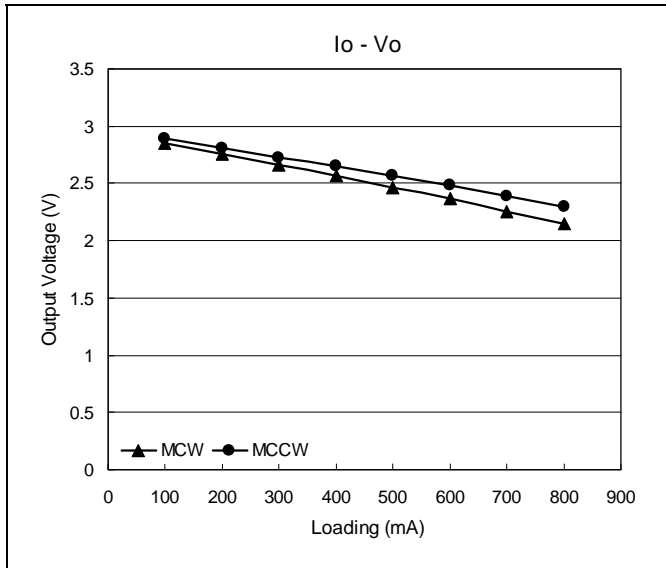


### NPN Transistor Characteristics Curve



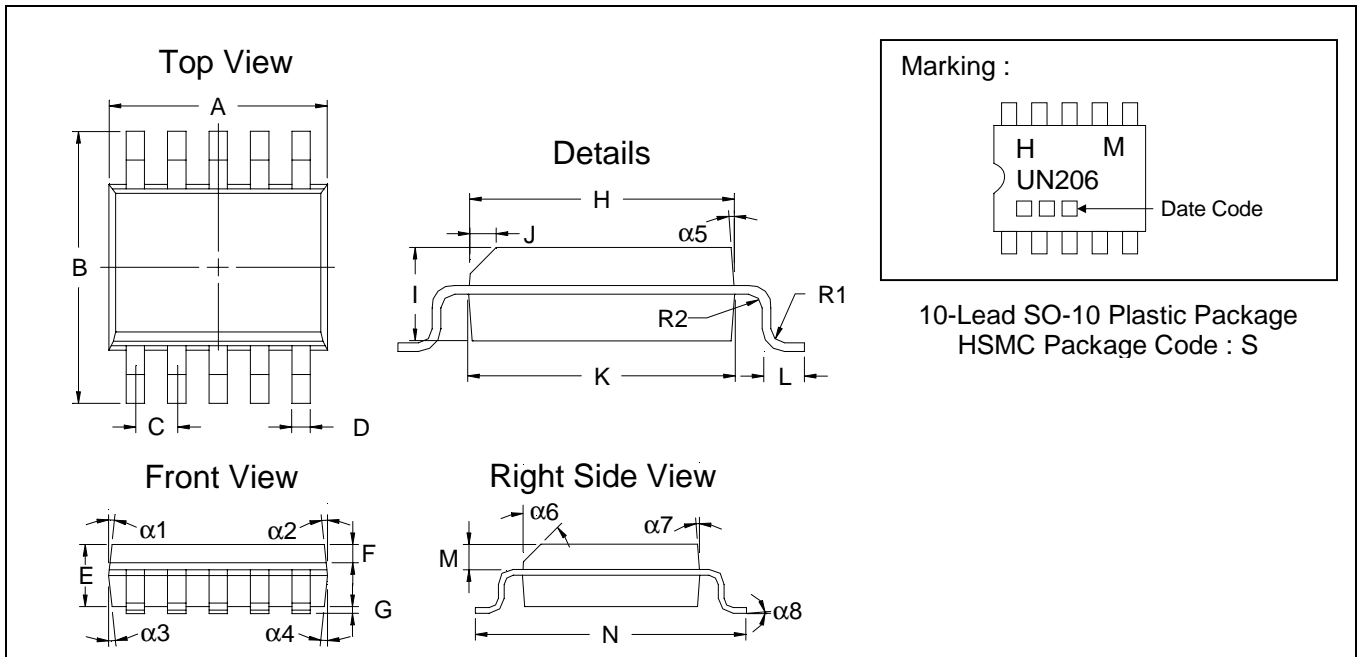


### Application Characteristics Curve





### SO-10 Dimension



\*:Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.188	0.192	4.775	4.877	L	0.020	0.026	0.508	0.660
B	0.230	0.242	5.842	6.147	M	0.024	0.028	0.610	0.711
C	0.034	0.038	0.864	0.965	N	0.230	0.242	5.842	6.147
D	0.014	0.018	0.356	0.457	$\alpha 1$	6°	8°	6°	8°
E	0.052	0.056	1.321	1.422	$\alpha 2$	6°	8°	6°	8°
F	0.014	0.018	0.356	0.457	$\alpha 3$	6°	8°	6°	8°
G	0.004	0.008	0.102	0.203	$\alpha 4$	6°	8°	6°	8°
H	0.148	0.152	3.759	3.861	$\alpha 5$	6°	8°	6°	8°
I	0.052	0.056	1.321	1.422	$\alpha 6$	44°	46°	44°	46°
J	0.014	0.018	0.356	0.457	$\alpha 7$	6°	8°	6°	8°
K	0.152	0.156	3.861	3.962	$\alpha 8$	3°	6°	3°	6°

**Notes :** 1.Dimension and tolerance based on our Spec. dated Aug. 01,1999.  
 2.Controlling dimension : millimeters.  
 3.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.  
 4.If there is any question with packing specification or packing method, please contact your local HSMC sales office.

**Material :**

- Lead : 42 Alloy ; solder plating
- Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0

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**Head Office And Factory :**

- **Head Office** (Hi-Sincerity Microelectronics Corp.) : 10F.,No. 61, Sec. 2, Chung-Shan N. Rd. Taipei Taiwan R.O.C.  
Tel : 886-2-25212056 Fax : 886-2-25632712, 25368454
- **Factory 1** : No. 38, Kuang Fu S. Rd., Fu-Kou Hsin-Chu Industrial Park Hsin-Chu Taiwan. R.O.C  
Tel : 886-3-5983621~5 Fax : 886-3-5982931
- **Factory 2** : No. 17-1, Ta-Tung Rd., Fu-Kou Hsin-Chu Industrial Park Hsin-Chu Taiwan. R.O.C  
Tel : 886-3-5977061 Fax : 886-3-5979220